



DMP2021UTSQ

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D max T _C = +25°C
001/	16mΩ @ V _{GS} = -4.5V	-18A
-20V	22mΩ @ V _{GS} = -2.5V	-15A

Description and Applications

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported up by a PPAP and is ideal for use in:

- Battery Management Application
- Power Management Functions
- DC-DC Converters

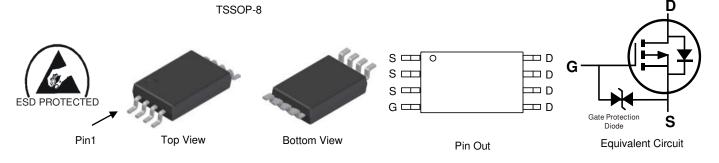
P-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low Gate Threshold Voltage
- Low On-Resistance
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: TSSOP-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Lead Frame. Solderable per MIL-STD-202, Method 208 (£3)
- Weight: 0.039 grams (Approximate)



Ordering Information (Notes 4 & 5)

Part Number	Case	Packaging
DMP2021UTSQ-13	TSSOP-8	2,500/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:



)'! = Manufacturer's Marking P2021U = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 17 = 2017) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	-20	V		
Gate-Source Voltage	V _{GSS}	±10	V		
	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	-7.4 -5.9	A
Continuous Drain Current (Note 7) $V_{GS} = -4.5V$	Steady State	$T_{C} = +25^{\circ}C$ $T_{C} = +70^{\circ}C$	ID	-18 -14	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	-55	A		
Continuous Source-Drain Diode Current (Note 7) T _A = +25°C			ls	-2	A
Pulsed Source-Drain Diode Current (10µs Pulse, Du	I _{SM}	-20	A		
Avalanche Current (Note 8) L = 0.1mH			las	-25	A
Avalanche Energy (Note 8) L = 0.1mH			E _{AS}	32	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 6)	T _A = +25°C	PD	0.9	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ heta JA}$	146	°C/W
Total Power Dissipation (Note 7)	T _A = +25°C	PD	1.3	W
Thermal Resistance, Junction to Ambient (Note 7) Steady S		$R_{ heta JA}$	95	°C/W
Thermal Resistance, Junction to Case (Note 7)	Steady State	R _{0JC}	16	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)	- 		- 76		•		
Drain-Source Breakdown Voltage	BV _{DSS}	-20	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current TJ = +25°C	IDSS		_	-1	μA	$V_{DS} = -20V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}		_	±10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)			•		•	·	
Gate Threshold Voltage	V _{GS(TH)}	-0.35	—	-1.0	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
			12	16		$V_{GS} = -4.5V, I_D = -4.5A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	—	15	22	mΩ	$V_{GS} = -2.5V, I_D = -4.5A$	
			19	40		V _{GS} = -1.8V, I _D = -2.5A	
Diode Forward Voltage	V _{SD}	—	-0.8	-1.2	V	V _{GS} = 0V, I _S = -1.0A	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss	_	2,760	-		V_{DS} = -15V, V_{GS} = 0V, f = 1.0MHz	
Output Capacitance	Coss	_	262	_	pF		
Reverse Transfer Capacitance	C _{rss}	_	220	_			
Gate Resistance	R _g	_	16	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	34	_			
Total Gate Charge (V _{GS} = -8V)	Qg	_	59	_	nC	$V_{DS} = -15V, I_D = -4.0A$	
Gate-Source Charge	Q _{gs}	_	3.5	_	no		
Gate-Drain Charge	Q _{gd}	_	8.3	_			
Turn-On Delay Time	t _{D(ON)}	_	7.5	_			
Turn-On Rise Time	t _R	_	25	_		$V_{DS} = -15V, V_{GS} = -4.5V,$	
Turn-Off Delay Time	t _{D(OFF)}		125	_	ns	$R_G = 1\Omega$, $I_D = -4.0A$	
Turn-Off Fall Time	tF	_	96	_]		
Reverse Recovery Time	t _{RR}		48	_	ns	I _F = -1.0A, di/dt = 100A/µs	
Reverse Recovery Charge	Q _{BB}		33	_	nC	I _F = -1.0A, di/dt = 100A/µs	

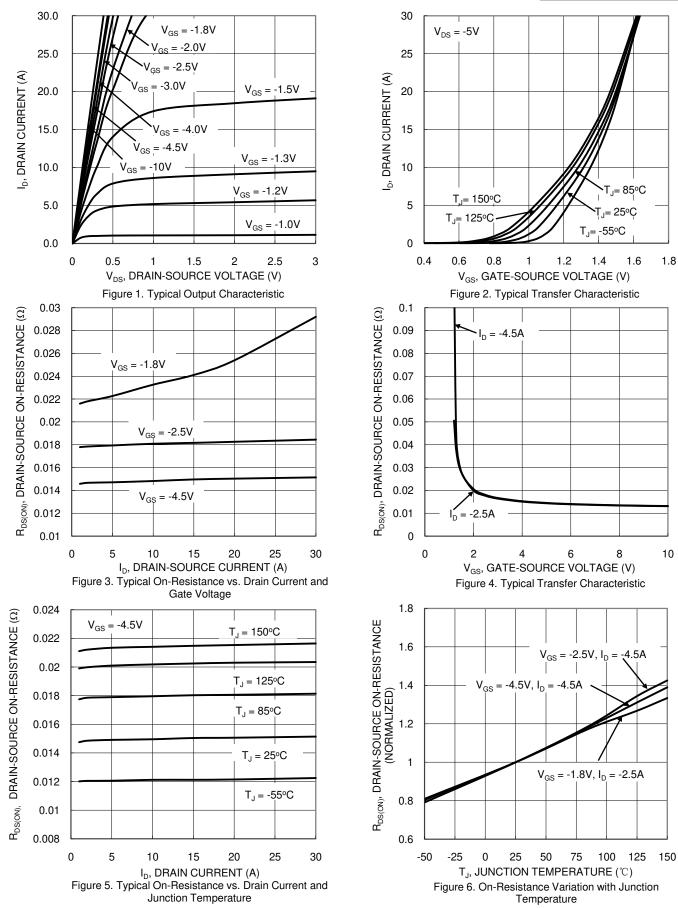
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

8. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.

9. Short duration pulse test used to minimize self-heating effect.
10. Guaranteed by design. Not subject to product testing.

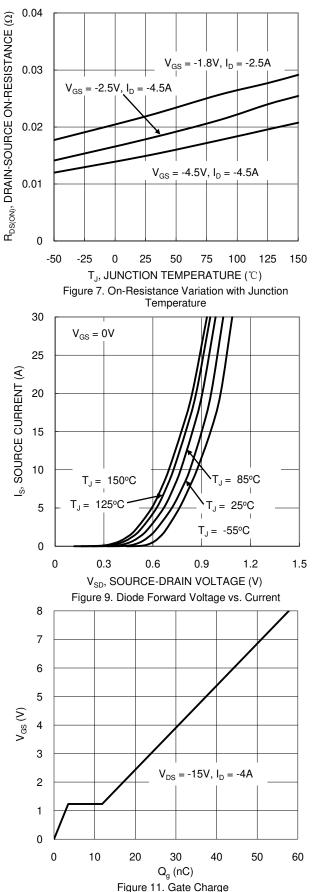


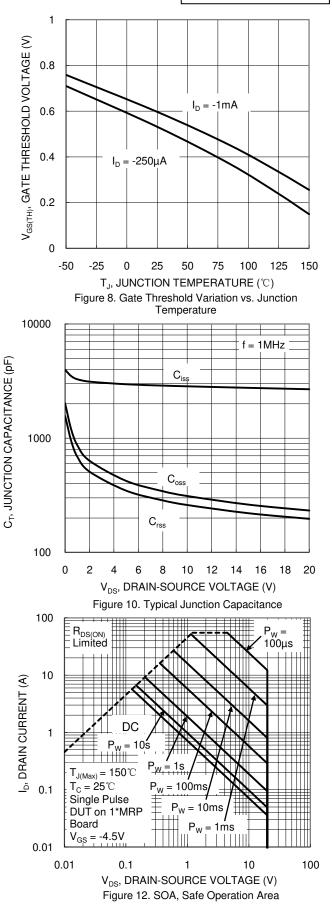
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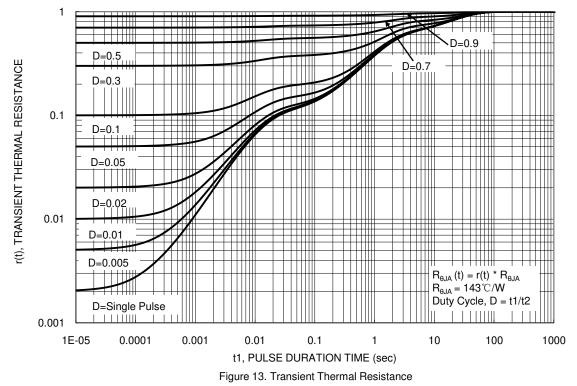










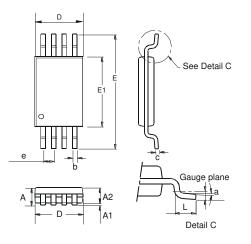




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

TSSOP-8

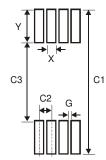


TSSOP-8					
Dim	Min	Max	Тур		
а	0.09	-	-		
Α	-	1.20	-		
A1	0.05	0.15	-		
A2	0.825	1.025	0.925		
b	0.19	0.30	-		
С	0.09	0.20	-		
D	2.90	3.10	3.025		
е	-	-	0.65		
Е	E – 6.40		6.40		
E1	4.30	4.50	4.425		
L	0.45	0.75	0.60		
AI	All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

TSSOP-8



Dimensions	Value (in mm)		
Х	0.45		
Y	1.78		
C1	7.72		
C2	0.65		
C3	4.16		
G	0.20		



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